

LC717A30UJ

Capacitance-Digital-Converter LSI for Electrostatic Capacitive Touch Sensors

The LC717A30UJ is a high performance, low cost, and highly usable capacitance converter for electrostatic capacitive touch and proximity sensors.

8 capacitance-sensing input channels ideal for use in any end products that needs an array of switches. The LC717A30UJ facilitates a short system development time through its automatic calibration function and minimal external components. The detection result (ON/OFF) for each sensor is read out by the serial interface (I²C or SPI).

Features

- Differential Capacitive Detection Using Mutual Capacitance
- Operates with Small to Large Capacitance Sensor Input Pads
- Capacitance Detection Down to Femto-Farad Level
- Measurement Time 16 ms for 8 Sensors
- Minimal External Components
- Selectable Interface: I²C or SPI
- Current Consumption: 0.8 mA (V_{DD} = 5.5 V)
- Supply Voltage: 2.6 V to 5.5 V
- AEC-Q100 Qualified and PPAP Capable

Typical Applications

- Automotive: Smart Key, Control Switches, Car Audio, Proximity
- Consumer: Home Appliance, White Goods, Induction Cooking
- Industrial: Security Lock
- Computing: PC Peripherals, Audio Visual Equipment
- Lighting: Remote Control Switches

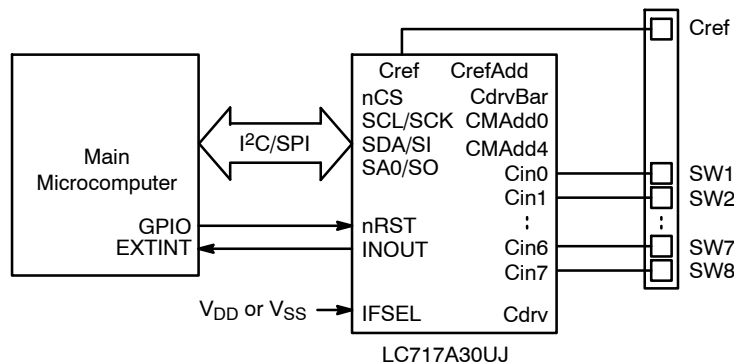
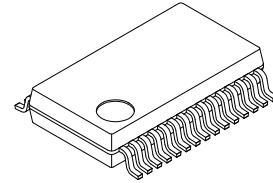


Figure 1. Application Schematic 1



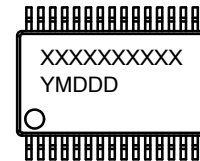
ON Semiconductor®

www.onsemi.com



SSOP30 (225 mil)
CASE 565AZ

MARKING DIAGRAM



XXXXX = Specific Device Code
Y = Year
M = Month
DDD = Additional Traceability Data

ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

LC717A30UJ

8 small capacitance sensors channels and 4-wire SPI interface.

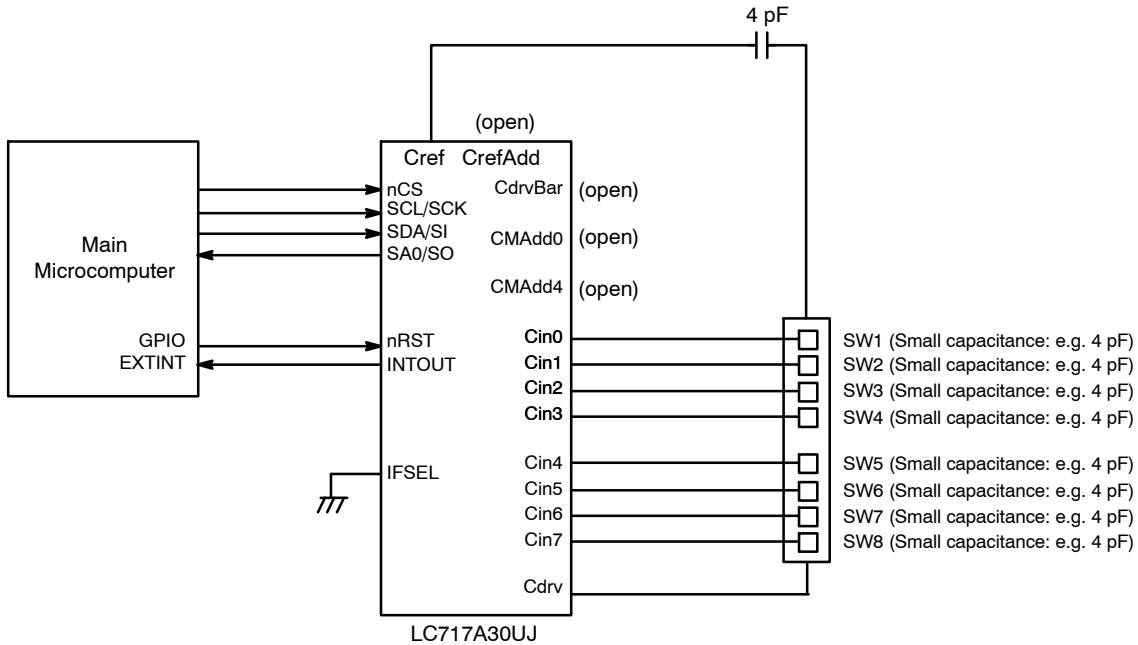


Figure 2. Application Schematic 2

8 Large capacitance sensors and I²C interface.

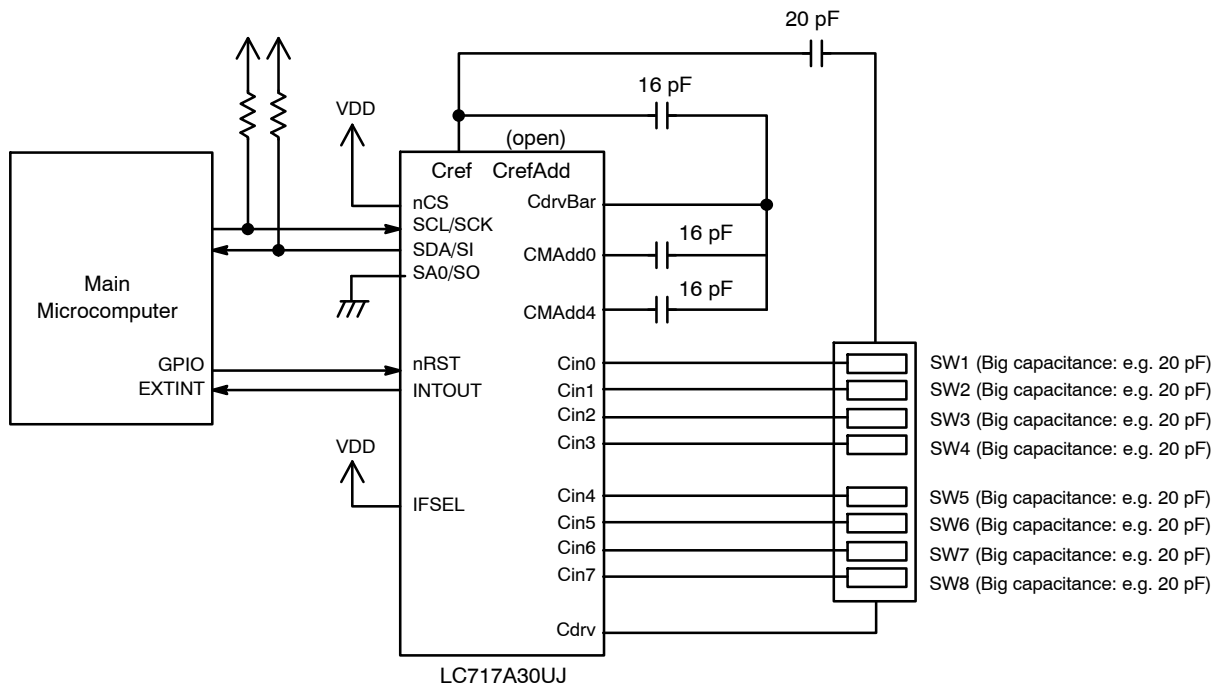


Figure 3. Application Schematic 3

LC717A30UJ

BLOCK DIAGRAM

The LC717A30UJ is a capacitance-digital converter LSI that can detect capacitance at the femto farad level. It consists a multiplexer that selects the input channels, a two-stage amplifier that detects the changes in the

capacitance and outputs analog-amplitude values, an A/D converter, a system clock, a power-on reset circuit, control logic and interface, I²C bus or SPI.

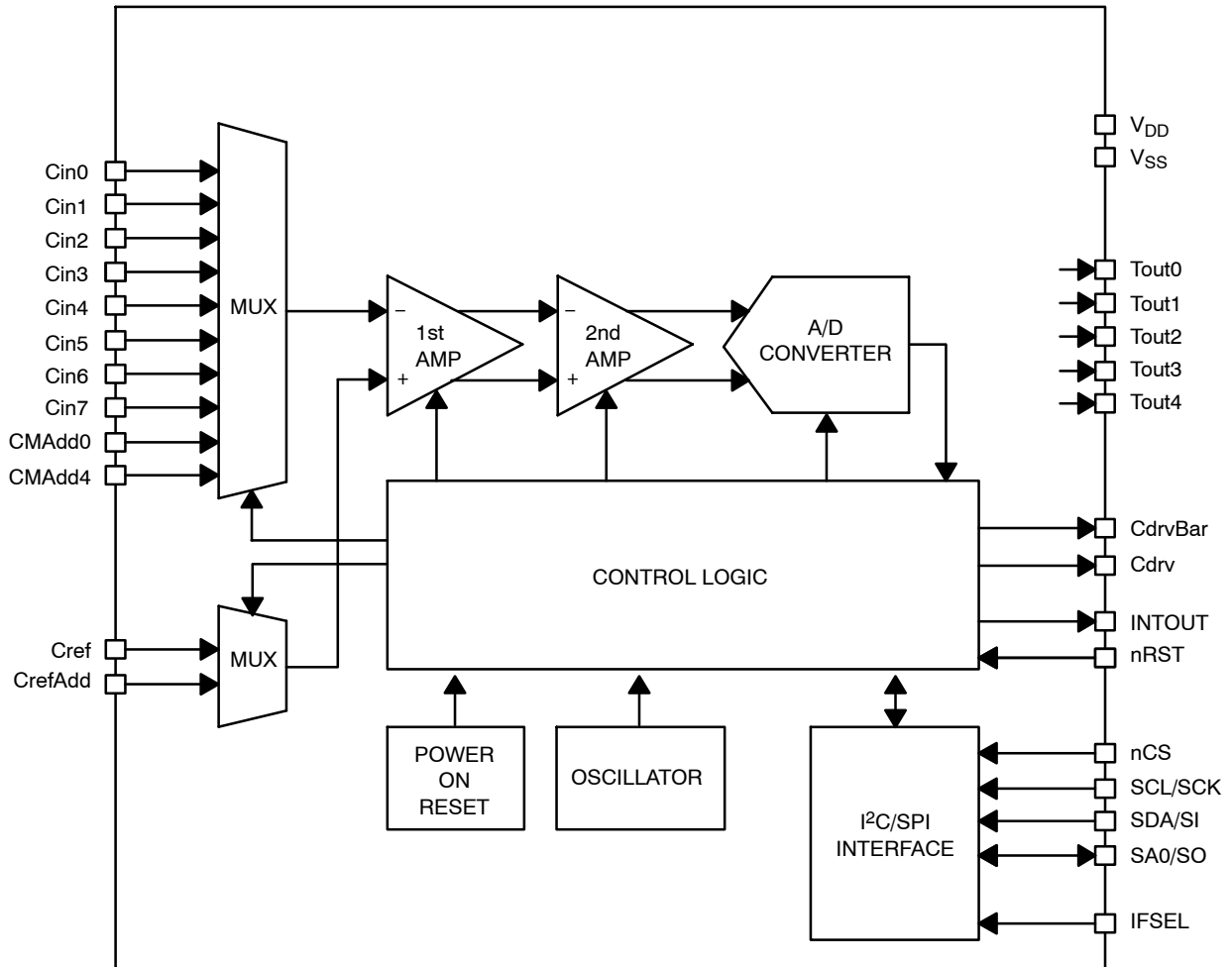


Figure 4. Simplified Block Diagram

LC717A30UJ

PIN ASSIGNMENT

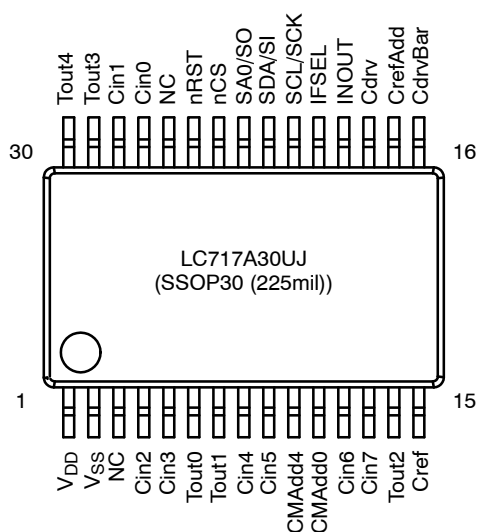


Figure 5. Pin Assignment (Top View)

Table 1. PIN ASSIGNMENT

Pin No.	Pin Name	I/O	Description
1	V _{DD}	Power	Power supply (+2.6 V to +5.5 V) (Note 1)
2	V _{SS}	Power	Ground (Notes 1, 2)
3	Non Connect	-	Connect to Ground
27	Cin0	I/O	Sensor inputs.
28	Cin1	I/O	Cin0 to Cin7 are connected to the inverting input of the 1st amplifier through the multiplexer.
4	Cin2	I/O	All unused input pins must remain open.
5	Cin3	I/O	Cdrv and Cin printed circuit board patterns should be close to each other as they are capacitively coupled.
8	Cin4	I/O	
9	Cin5	I/O	
12	Cin6	I/O	
13	Cin7	I/O	
6	Tout0	O	Test pin, must remain open
7	Tout1	O	Test pin, must remain open
10	CMAAdd4	I/O	Offset capacitance input pin for the sensor inputs 4 to 7. When using large sensor pads with high capacitance, additional capacitance is added between CMAAdd4 and CdrvBar. See Figure 3. Remain open if not in use.
11	CMAAdd0	I/O	Offset capacitance input pin for the sensor inputs 0 to 3. When using large sensor pads with high capacitance, additional capacitance is added between CMAAdd4 and CdrvBar. See Figure 3. Remain open if not in use.
14	Tout2	O	Test pin, must remain open
15	Cref	I/O	Reference capacitance input pins. See Figures 2 and 3.
17	CrefAdd	I/O	When using large sensor pads with high capacitance, additional capacitance maybe added for Cref. See Figure 3. Remain open if not in use.

LC717A30UJ

Table 1. PIN ASSIGNMENT (continued)

Pin No.	Pin Name	I/O	Description
16	CdrvBar	O	Capacitance sensors drive signal inversion output. When using large sensor pads with high capacitance, additional capacitance is added between CMAAdd0 and CMAAdd4 and CdrvBar. See Figure 3. Remain open if not in use.
18	Cdrv	O	Capacitance sensors drive output. Cdrv and Cin printed circuit board patterns should be close to each other as they are capacitively coupled.
19	INTOUT	O	Interrupt output pin. (Active high) Remain open if not in use
20	IFSEL	I	Interface Select. IFSEL = "Low" (V_{SS}): SPI mode IFSEL = "High" (V_{DD}): I ² C mode
21	SCL/SCK	I	I ² C = SCL clock input SPI = SCK clock input
22	SDA/SI	I/O	I ² C = SDA data input/output SPI = SI data input
23	SA0/SO	I/O	I ² C = SA0 slave address selection input SPI = SO data output
24	nCS	I	I ² C = "High" (V_{DD}) SPI = nCS chip select inversion input
25	nRST	I	Reset signal inversion input pin. nRST = "Low" (V_{SS}), in reset state Cin0 to Cin7, CMAAdd0, CMAAdd4, Cref, CrefAdd, CdrvBar and Tout0 to Tout4 are "Hi-Z"
26	Non Connect	-	Connect to Ground
29	Tout3	O	Test pin, must remain open
30	Tout4	O	Test pin, must remain open

- For noise de-coupling place a high-valued capacitor and a low-valued capacitor in parallel between V_{DD} and V_{SS} . The small-valued capacitor, at least 0.1 μ F, should be mounted near the LSI.
- When V_{SS} terminal is not grounded, in battery-powered mobile equipment, detection sensitivity may be degraded.

Table 2. PIN FUNCTIONS

Pin No.	Pin Name	I/O	Pin Functions	Pin Type
1	V_{DD}	Power	Power supply (+2.6 V to +5.5 V)	
2	V_{SS}	Power	Ground	
27	Cin0	I/O	Capacitance sensor input 0	<p>The diagram shows a pin connected to V_{DD} through a diode and to V_{SS} through another diode. A resistor R is connected to the pin, which is also connected to an AMP and a Buffer.</p>
28	Cin1	I/O	Capacitance sensor input 1	
4	Cin2	I/O	Capacitance sensor input 2	
5	Cin3	I/O	Capacitance sensor input 3	
8	Cin4	I/O	Capacitance sensor input 4	
9	Cin5	I/O	Capacitance sensor input 5	
12	Cin6	I/O	Capacitance sensor input 6	
13	Cin7	I/O	Capacitance sensor input 7	
10	CMAAdd4	I/O	Additional offset capacitance input pin for the sensor inputs 4 to 7	
11	CMAAdd0	I/O	Additional offset capacitance input pin for the sensor inputs 0 to 3	
15	Cref	I/O	Reference capacitance input	
17	CrefAdd	I/O	Additional Reference capacitance input	

LC717A30UJ

Table 2. PIN FUNCTIONS (continued)

Pin No.	Pin Name	I/O	Pin Functions	Pin Type
6	Tout0	O	Output for tests	
7	Tout1	O	Output for tests	
14	Tout2	O	Output for tests	
29	Tout3	O	Output for tests	
30	Tout4	O	Output for tests	
16	CdrvBar	O	Capacitance sensors drive signal inversion output	
18	Cdrv	O	Capacitance sensors drive output	
19	INTOUT	O	Interrupt output	
20	IFSEL	I	Switching control input of the serial data communication interface	
21	SCL/SCK	I	SCL clock input (I ² C)	
		I	SCK clock input (SPI)	
24	nCS	I	nCS chip select inversion input (SPI)	
25	nRST	I	External reset signal inversion input	
22	SDA/SI	I/O	SDA data input/output (I ² C)	
		I	SI data input (SPI)	
23	SA0/SO	I	SA0 slave address selection input (I ² C)	
		O	SO data output (SPI)	

LC717A30UJ

ABSOLUTE MAXIMUM RATINGS (V_{SS} = 0 V, T_A = +25°C)

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage Range	-0.3 to +6.5	V
V _{IN}	Input Voltage Range (Note 3)	-0.3 to V _{DD} +0.3	V
V _{OUT}	Output Voltage Range (Note 4)	-0.3 to V _{DD} +0.3	V
I _{OP}	Peak Output Current Range (Notes 4, 5)	-8.0 to +8.0	mA
I _{OA}	Total Outputs Current Range (Note 6)	-40 to +40	mA
P _{dmax}	Maximum Power Dissipation (Note 7)	160	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Apply to Cin0 to Cin7, CMAAdd0, CMAAdd4, Cref, CrefAdd, SCL/SCK, SDA/SI, SA0, nCS, nRST, IFSEL.
- Apply to Cdrv, CdrvBar, SDA, SO, INTOUT, Tout0 to Tout4.
- Total value with duty cycle under 25%.
- Limited to one pin, with duty cycle under 50%.
- T_A = 105°C, Single-layer glass epoxy board (76.1 × 114.3 × 1.6 mm).

RECOMMENDED OPERATING CONDITIONS (V_{SS} = 0 V)

Symbol	Parameter	Min	Max	Unit
V _{DD}	Operating Supply Voltage Range (Note 8)	2.6	5.5	V
V _{IH}	Input High-level Voltage Range (Note 9)	0.8 V _{DD}	V _{DD}	V
V _{IL}	Input Low-level Voltage Range (Note 9)	0	0.2 V _{DD}	V
T _A	Ambient Temperature Range	-40	105	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

- For noise de-coupling place a high-valued capacitor and a low-valued capacitor in parallel between V_{DD} and V_{SS}. The small-valued capacitor, at least 0.1 μF, should be mounted near the LSI. In addition, it is recommended that the power supply ripple + noise is less than ±40 mV.
- Apply to SCL/SCK, SDA/SI, SA0, nCS, nRST, IFSEL.

ELECTRICAL CHARACTERISTICS

(V_{DD} = 2.6 to 5.5 V, V_{SS} = 0 V, T_A = -40 to + 105°C, Unless otherwise specified, the Cdrv drive frequency is f_{CDRV} = 121 kHz.)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
COMMON						
V _{OH1}	Output High-level Voltage (Note 10)	I _O = -1.5 mA, V _{DD} = 2.6 to 3.6 V	0.8 V _{DD}	-	-	V
V _{OH2}		I _O = -3.0 mA, V _{DD} = 3.6 to 5.5 V	0.8 V _{DD}	-	-	V
V _{OL1}	Output Low-level Voltage (Note 10)	I _O = +1.5 mA, V _{DD} = 2.6 to 3.6 V	-	-	0.2 V _{DD}	V
V _{OL2}		I _O = +3.0 mA, V _{DD} = 3.6 to 5.5 V	-	-	0.2 V _{DD}	V
V _{OL3}	Tout0 to Tout4 pins Output Low-level Voltage	I _O = +1.5 mA	-	-	0.2 V _{DD}	V
V _{OL4}	SDA pin Output Low-level Voltage	I _O = +3.0 mA	-	-	0.4	V
I _{IH}	Input High-level Current (Note 11)	V _I = V _{DD}	-	-	1.0	μA
I _{IL}	Input Low-level Current (Note 11)	V _I = V _{SS}	-1.0	-	-	μA
I _{OFF}	Output Off Leakage Current (Note 12)	V _I = V _{DD} or V _I = V _{SS}	-1.0	-	1.0	μA
I _{DD1}	Current Consumption	Initial setting, Long interval operation, Sensor pins are open (Note 13), V _{DD} = 5.5 V	-	0.8	2.2	mA
I _{DD2}		Initial setting, Short interval operation, Sensor pins are open (Note 13), V _{DD} = 5.5 V	-	3.25	6.5	mA
I _{STBY}		Sleep mode (Sleep period) Sensor pins are open (Note 13)	-	0.1	70	μA

LC717A30UJ

ELECTRICAL CHARACTERISTICS (continued)

($V_{DD} = 2.6$ to 5.5 V, $V_{SS} = 0$ V, $T_A = -40$ to $+105^\circ\text{C}$, Unless otherwise specified, the Cdrv drive frequency is $f_{CDRV} = 121$ kHz.)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
--------	-----------	-----------	-----	-----	-----	------

CAPACITANCE SENSOR FUNCTION

$C_{inSENSE}$	Cin Detection Sensitivity	Measurements conducted using the test mode in the LSI, Minimum gain setting	0.0476	0.068	0.0884	LSB/FF
I_{Cin}	Sensor Pin Leakage Current (Note 14)	$V_I = V_{DD}$ or $V_I = V_{SS}$	–	± 25	± 500	nA
f_{CDRV}	Cdrv Drive Frequency	With 121 kHz setting	84.85	121.21	157.57	kHz

POWER-ON RESET FUNCTION

t_{NRST}	nRST Minimum Pulse Width		1.0	–	–	μs
t_{POR}	Power-on Reset Time		–	–	20	ms
t_{POROP}	Power-on Reset Operation Condition: Hold Time		10	–	–	ms
V_{POROP}	Power-on Reset Operation Condition: Input Voltage		–	–	0.1	V
t_{VDD}	Power-on Reset Operation Condition: Power Supply Rise Rate	0 V to V_{DD}	1.0	–	–	V/ms

INTERVAL OPERATION TIMING

T_{LIVAL1}	Long Interval Time	$V_{DD} = 2.6$ to 4.5 V, Long interval mode (Long interval time is set to 101 ms)	35	101	145	ms
T_{LIVAL2}		$V_{DD} = 4.5$ to 5.5 V, Long interval mode (Long interval time is set to 101 ms)	40	101	125	ms
T_{SIVAL1}	Short Interval Time	$V_{DD} = 2.6$ to 4.5 V, Short interval mode (Short interval time is set to 5 ms)	1.7	5	7.3	ms
T_{SIVAL2}		$V_{DD} = 4.5$ to 5.5 V, Short interval mode (Short interval time is set to 5 ms)	1.9	5	6.3	ms

I²C COMPATIBLE BUS INTERFACE TIMING

f_{SCL}	SCL Clock Frequency	SCL	–	–	400	kHz
$t_{HD; STA}$	START Condition Hold Time	SCL, SDA	0.6	–	–	μs
t_{LOW}	SCL Clock Low Period	SCL	1.3	–	–	μs
t_{HIGH}	SCL Clock High Period	SCL	0.6	–	–	μs
$t_{SU; STA}$	Repeated START Condition Setup Time	SCL, SDA	0.6	–	–	μs
$t_{HD; DAT}$	Data Hold Time	SCL, SDA	0	–	0.9	μs
$t_{SU; DAT}$	Data Setup Time	SCL, SDA	0.5	–	–	μs
t_r/t_f	SDA, SCL Rise/Fall Time	SCL, SDA	–	–	0.3	μs
$t_{SU; STO}$	STOP Condition Setup Time	SCL, SDA	0.6	–	–	μs
t_{BUF}	STOP-to-START Bus Release Time	SCL, SDA	2.5	–	–	μs

SPI INTERFACE TIMING

f_{SCK}	SCK Clock Frequency	SCK	–	–	5.0	MHz
t_{LOW}	SCK Clock Low Time	SCK	100	–	–	ns
t_{HIGH}	SCK Clock High Time	SCK	100	–	–	ns
t_r/t_f	Input Signal Rise/Fall Time	nCS, SCK, SI	–	–	300	ns
$t_{SU; NCS}$	nCS Setup Time	nCS, SCK	200	–	–	ns
$t_{SU; SCK}$	SCK Clock Setup Time	nCS, SCK	100	–	–	ns
$t_{SU; SI}$	Data Setup Time	SCK, SI	100	–	–	ns
$t_{HD; SI}$	Data Hold Time	SCK, SI	100	–	–	ns

LC717A30UJ

ELECTRICAL CHARACTERISTICS (continued)

($V_{DD} = 2.6$ to 5.5 V, $V_{SS} = 0$ V, $T_A = -40$ to $+105^\circ\text{C}$, Unless otherwise specified, the Cdrv drive frequency is $f_{CDRV} = 121$ kHz.)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
--------	-----------	-----------	-----	-----	-----	------

SPI INTERFACE TIMING

$t_{HD;NCS}$	nCS Hold Time	nCS, SCK	200	–	–	ns
$t_{HD;SCK}$	SCK Clock Hold Time	nCS, SCK	700	–	–	ns
t_{CPH}	nCS Standby Pulse Width	nCS	300	–	–	ns
t_{CHZ}	Output High Impedance Time from nCS	nCS, SO	–	–	100	ns
t_V	Output Data Determination Time	SCK, SO	–	–	100	ns
$t_{HD;SO}$	Output Data Hold Time	SCK, SO	0	–	–	ns
t_{CLZ}	Output Low Impedance Time from SCK Clock	SCK, SO	100	–	–	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

10. Apply to Cdrv, CdrvBar, SO, INTOUT.

11. Apply to SCL/SCK, SDA/SI, SA0, nCS, nRST, IFSEL.

12. Apply to Cdrv, CdrvBar, SDA, SO.

13. Sensor pins (Cin0 to Cin7, CMAAdd0, CMAAdd4, Cref, CrefAdd) are open condition.

14. Apply to Cin0 to Cin7, CMAAdd0, CMAAdd4, Cref, CrefAdd.

Table 3. ORDERING INFORMATION

Device	Package	Shipping (Qty / Packing) [†]
LC717A30UJ-AH	SSOP30 (225 mil) (Pb-Free / Halogen Free)	1000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

FUNCTIONAL DESCRIPTION

Power-on Reset (POR)

When power is turned on, power-on reset is enabled, it is released after power-on reset time, t_{POR} . Power-on reset operation condition; Power supply rise rate t_{VDD} must be at least 1.0 V/ms.

Since INTOUT pin changes from “High” to “Low” at the same time as reset release, it is possible to verify the timing of release of reset externally. During power-on reset, Cin0 to Cin7, CMAAdd0, CMAAdd4, Cref, CrefAdd, and CdrvBar are unknown.

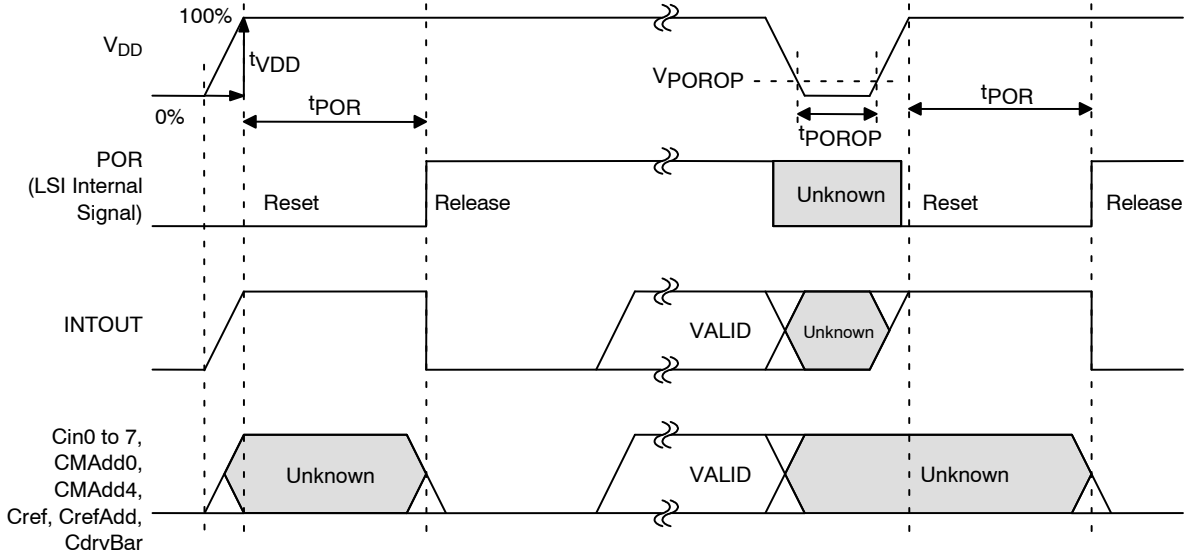


Figure 6. Power-on Sequence by the Power-on Reset

External Reset (nRST)

Reset State nRST = “Low”. Pins Cin0 to Cin7, CMAAdd0, CMAAdd4, Cref, CrefAdd and CdrvBar, are “Hi-Z” during reset state. The reset state is released after t_{POR} .

Since INTOUT pin changes from “High” to “Low” at the same time as the released of reset, it is possible to verify the timing of release of reset externally.

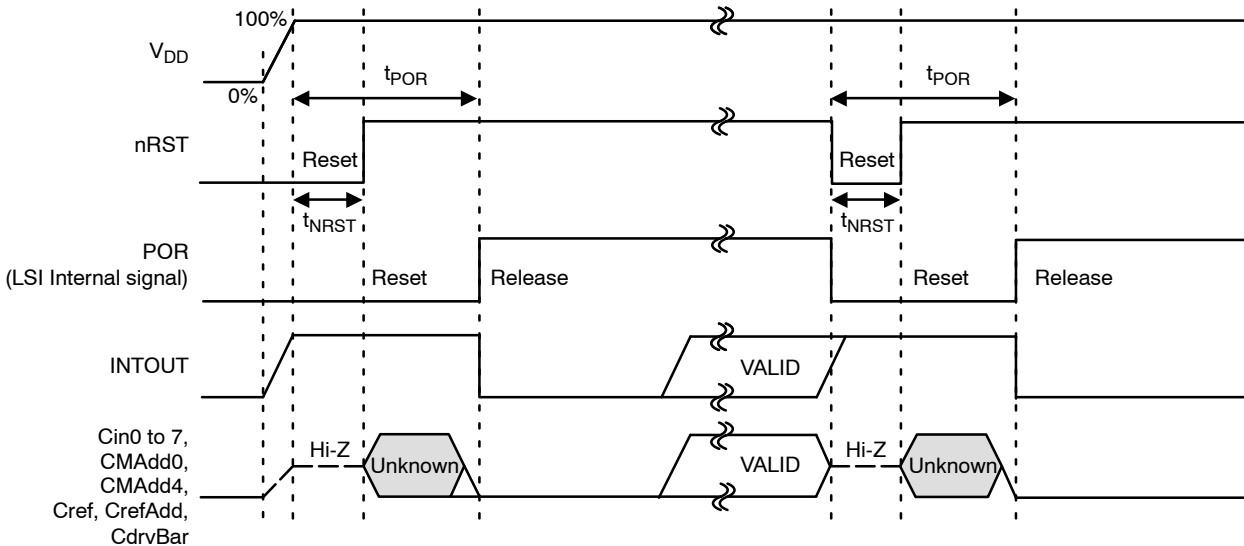


Figure 7. Power-on Sequence by the External Reset

LC717A30UJ

I²C Data Timing

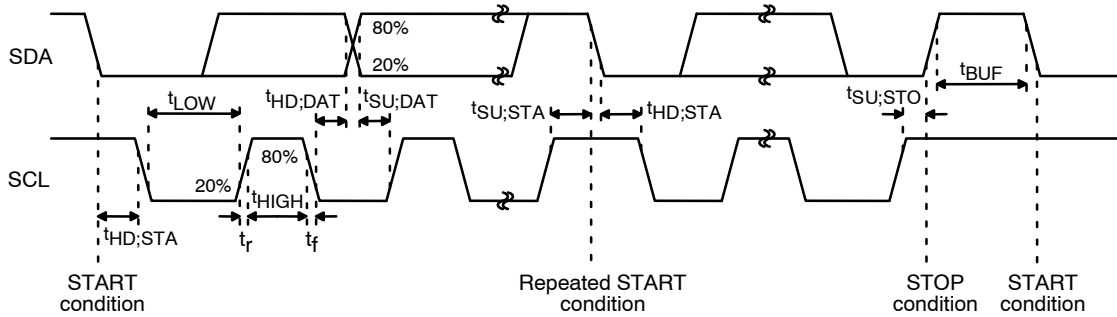


Figure 8. I²C Data Timing

I²C Communication Formats

Write Format

When using the Write format of I²C the data can be written into sequentially incremented addresses.



Figure 9. I²C Write Format

Read Format

When using the Read format of I²C the data can be read from sequentially incremented addresses.

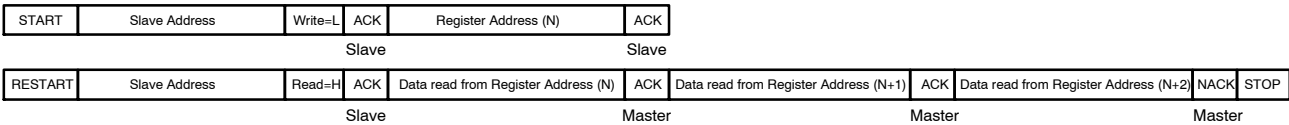


Figure 10. I²C Read Format

I²C Slave Address

SA0 pin is used to select the slave address

Table 4. I²C SLAVE ADDRESS

SA0 Pin Input	7 bit Slave Address	Binary Notation	8 bit Slave Address
Low	0x16	00101100b (Write)	0x2C
		00101101b (Read)	0x2D
High	0x17	00101110b (Write)	0x2E
		00101111b (Read)	0x2F

SPI Data Timing (Mode 0/Mode 3)

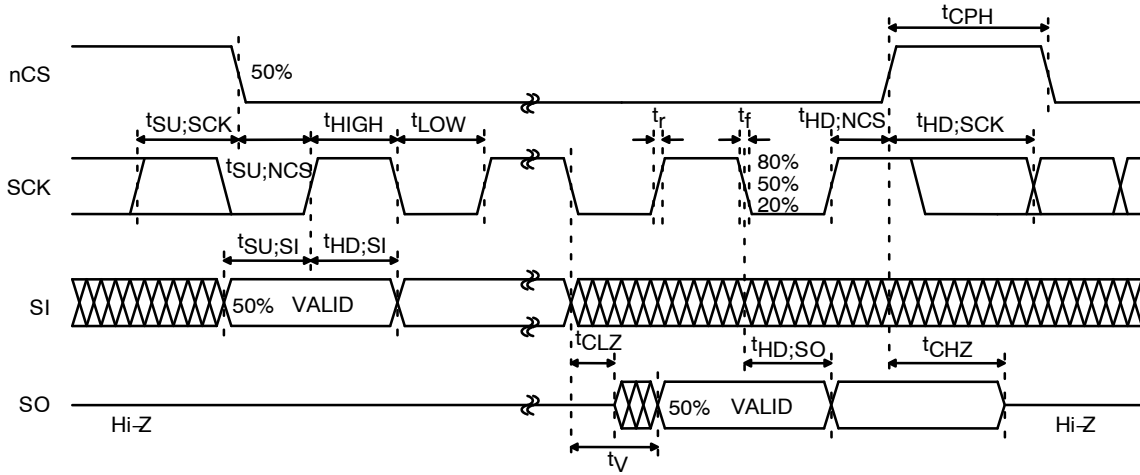


Figure 11. SPI Data Timing

SPI Write Format (Example of Mode 0)

When using the SPI Write format the data can be written into sequentially incremented addresses with preserving nCS = "L".

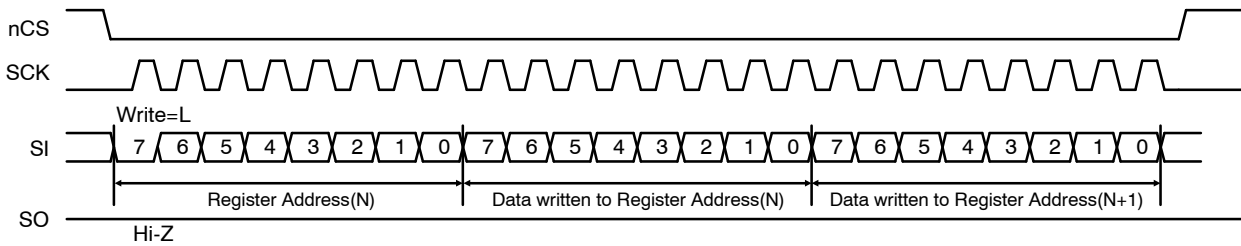


Figure 12. SPI Write Format

SPI Read Format

When using the SPI Read format the data can be read from sequentially incremented addresses with preserving nCS = "L".

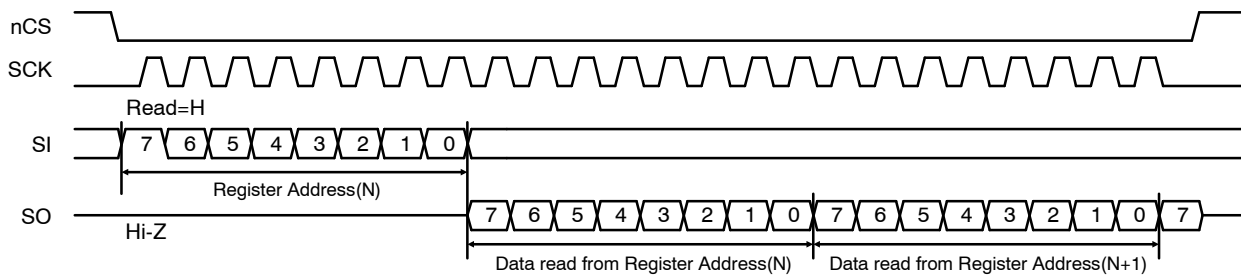
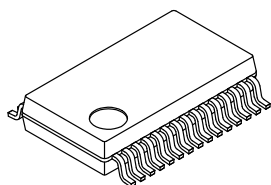


Figure 13. SPI Read Format

MECHANICAL CASE OUTLINE

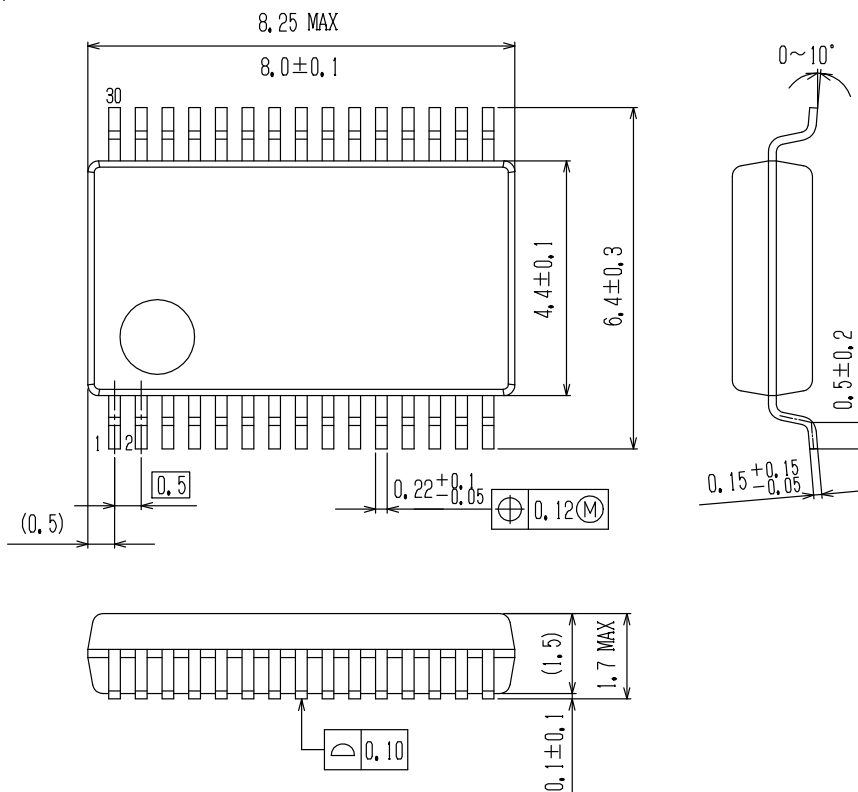
PACKAGE DIMENSIONS

ON Semiconductor®

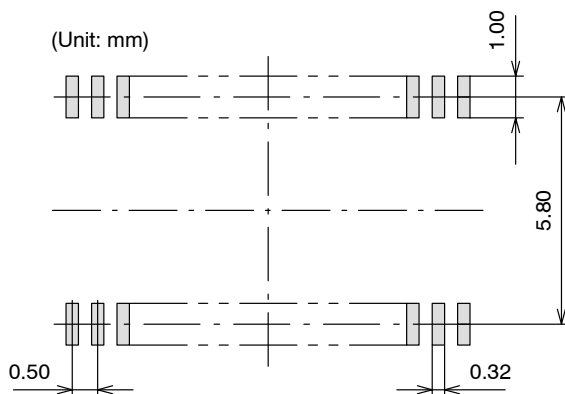


SSOP30 (225 mil)
CASE 565AZ
ISSUE A

DATE 25 OCT 2013



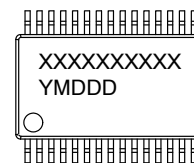
SOLDERING FOOTPRINT*



NOTE: The measurements are not to guarantee but for reference only.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
 Y = Year
 M = Month
 DDD = Additional Traceability Data

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

DOCUMENT NUMBER:	98AON80824E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SSOP30 (225 MIL)	PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:
Voice Mail: 1 800-282-9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

